

描述 / Descriptions

TO-220FL 塑封封装 N 沟道 MOS 场效应管。N-CHANNEL MOSFET in a TO-220FL Plastic Package.

特征 / Features

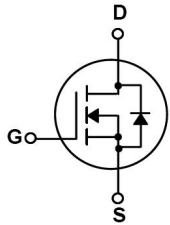
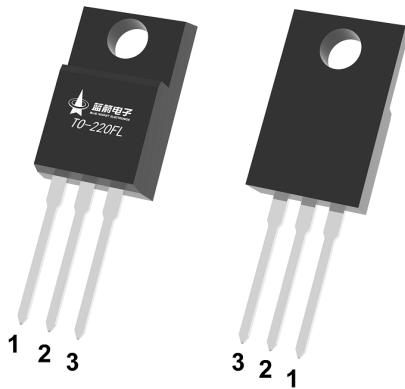
低栅电荷,低反馈电容,开关速度快。

Low gate charge, low crss, fast switching.

用途 / Applications

用于高功率 DC/DC 转换和功率开关。

These devices are well suited for high efficiency switching DC/DC converters.

内部等效电路 / Equivalent Circuit**引脚排列 / Pinning**

PIN1 : G

PIN 2 : D

PIN 3 : S

印章代码 / Marking

见印章说明。See Marking Instructions.

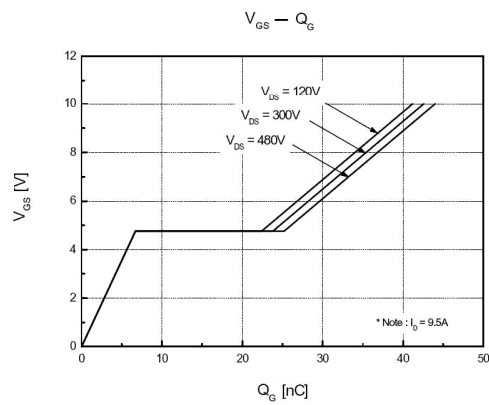
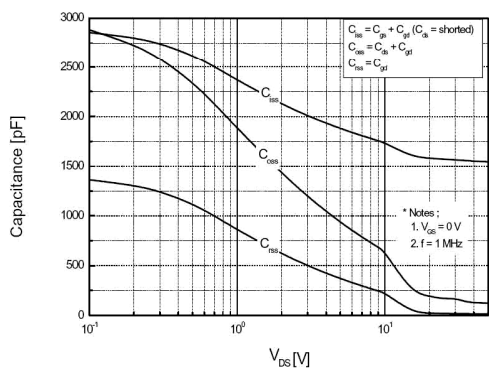
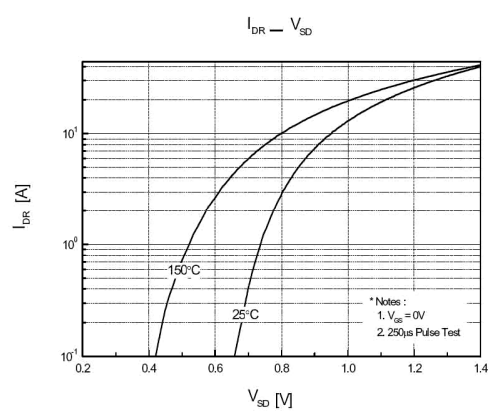
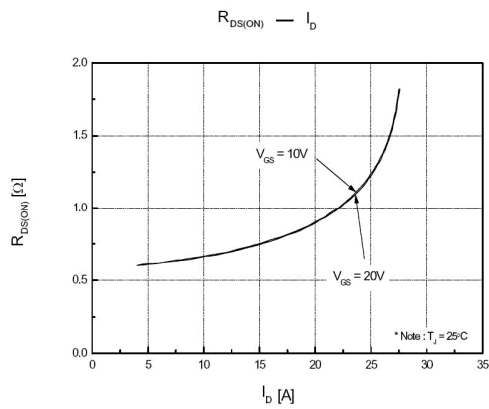
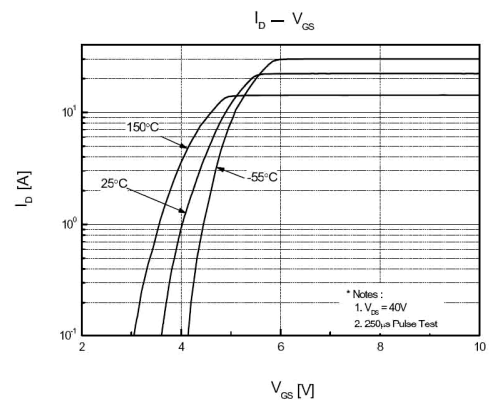
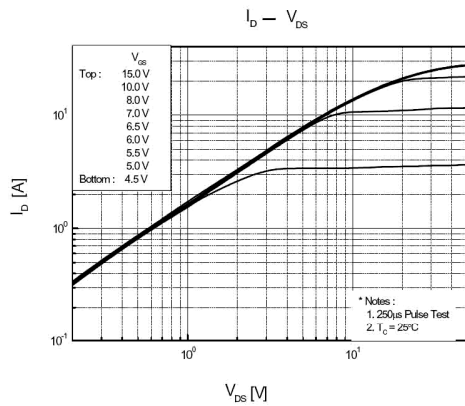
极限参数 / Absolute Maximum Ratings(Ta=25°C)

参数 Parameter	符号 Symbol	数值 Rating	单位 Unit
Drain-Source Voltage	V_{DS}	650	V
Drain Current	$I_D(T_C=25^{\circ}\text{C})$	10	A
Drain Current	$I_D(T_C=100^{\circ}\text{C})$	5.7	A
Drain Current - Pulsed	I_{DM}	38	A
Gate-Source Voltage	V_{GS}	± 30	V
Single Pulsed Avalanche Energy	E_{AS}	700	mJ
Repetitive Avalanche Energy	E_{AR}	15.6	mJ
Avalanche Current	I_{AR}	9.5	A
Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.5	$^{\circ}\text{C}/\text{W}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	$^{\circ}\text{C}/\text{W}$
Power Dissipation	$P_D(T_C=25^{\circ}\text{C})$	50	W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to 150	$^{\circ}\text{C}$

电性能参数 / Electrical Characteristics(Ta=25°C)

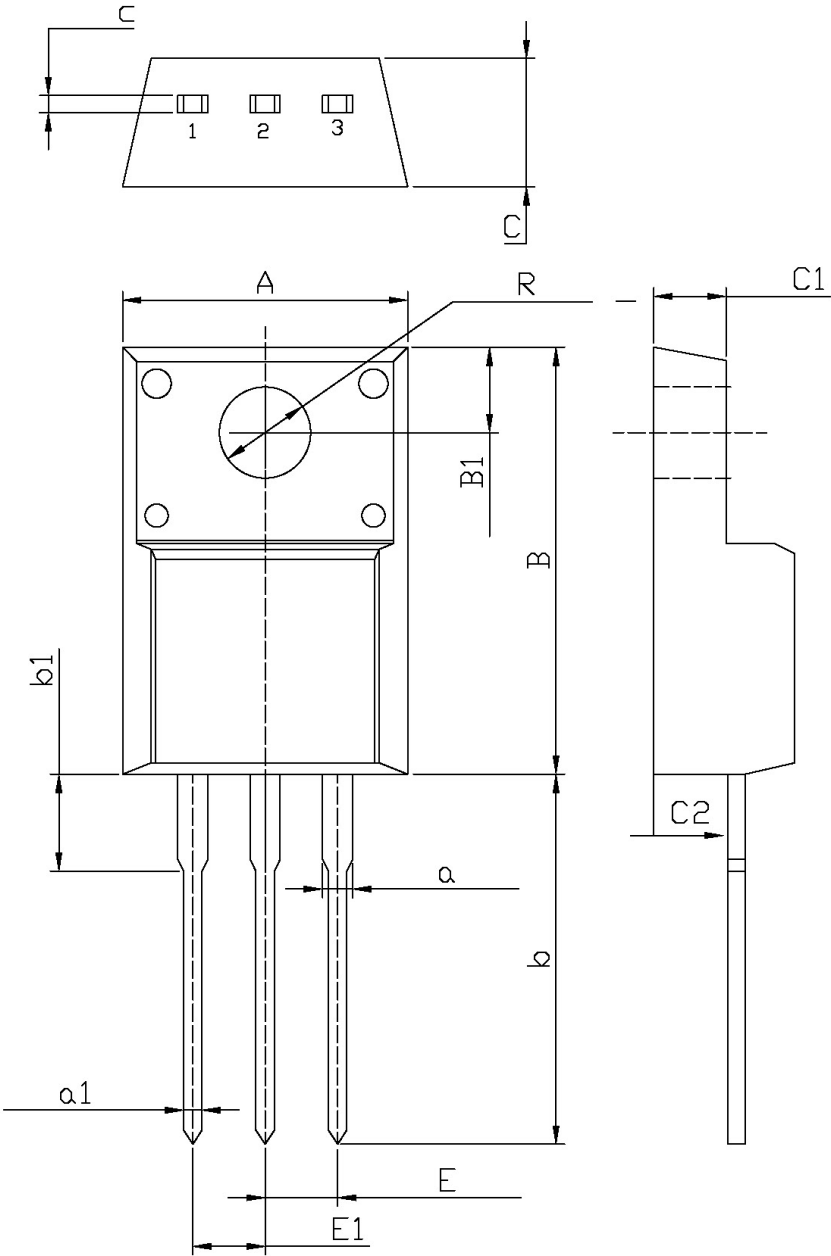
参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Drain-Source Breakdown Voltage	BV_{DS}	$V_{GS}=0V$ $I_D=250\mu A$	650			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=600V$ $V_{GS}=0V$			1.0	μA
		$V_{DS}=480V$ $T_C=125^{\circ}\text{C}$			10	μA
Gate-Body Leakage Current Forward	I_{GSS}	$V_{GS}=\pm 30V$ $V_{DS}=0V$			± 10	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu A$	2.0		4.0	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V$ $I_D=4.75A$		0.74	0.85	Ω
Forward Transconductance	g_{FS}	$V_{DS}=40V$ $I_D=4.75A$		8.0		S
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V$ $I_S=9.5A$			1.4	V
Input Capacitance	C_{iss}	$V_{DS}=25V$ $V_{GS}=0V$ $f=1.0\text{MHz}$		1570	2040	pF
Output Capacitance	C_{oss}			166	215	pF
Reverse Transfer Capacitance	C_{rss}			18	24	pF
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=300V$ $I_D=9.5A$ $R_G=25\Omega$		23	55	ns
Turn-On Rise Time	t_r			69	150	ns
Turn-Off Delay Time	$t_{d(off)}$			144	300	ns
Turn-Off Fall Time	t_f			77	165	ns

电参数曲线图 / Electrical Characteristic Curve

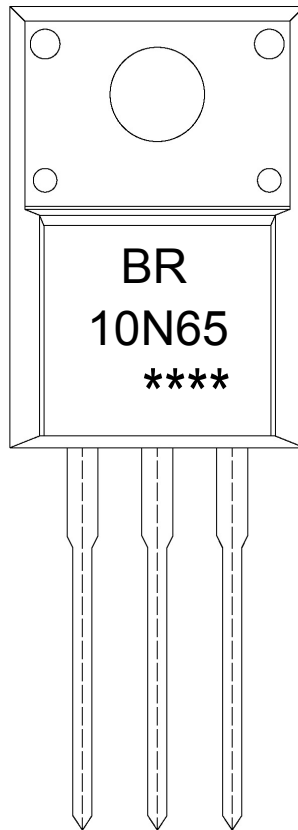


外形尺寸图 / Package Dimensions

TO-220FL 单位：mm



Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
C	4.5	4.9	b1	2.90	3.90
C	0.4	0.6	a	1.08	1.48
A	9.96	10.36	a1	0.70	0.90
B	15.67	16.07	E	2.34	2.74
B1	3.30	3.50	E1	2.34	2.74
R	3.08	3.28	C1	2.34	2.74
b	12.48	13.48	C2	2.56	2.96

印章说明 / Marking Instructions

说明：

BR： 为公司代码

10N65： 为型号代码

****： 为生产批号代码，随生产批号变化

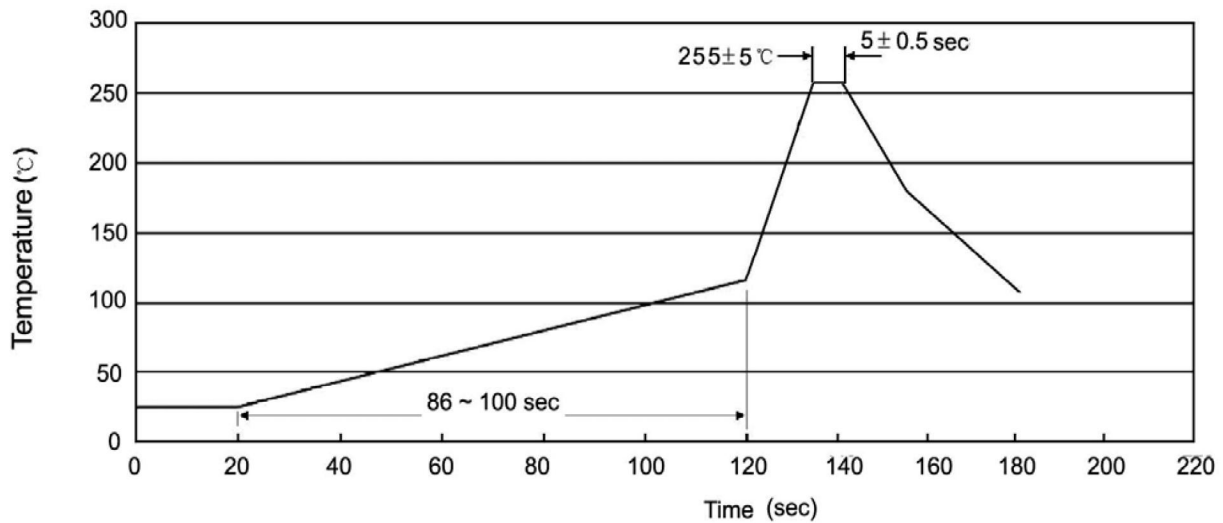
Note:

BR: Company Code

10N65: Product Type

****: Lot No. Code, code change with Lot No

波峰焊温度曲线图(无铅) / Temperature Profile for Dip Soldering(Pb-Free)



说明：

- 1、预热温度 25 ~ 150°C，时间 60 ~ 90sec;
- 2、峰值温度 255±5°C，时间持续为 5±0.5sec;
- 3、焊接制程冷却速度为 2 ~ 10°C/sec.

Note:

- 1.Preheating:25~150°C, Time:60~90sec.
- 2.Peak Temp.:255±5°C, Duration:5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions

温度：270±5°C

时间：10±1 sec.

Temp.:270±5°C

Time:10±1 sec

包装规格 / Packaging SPEC.

套管包装 / TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
TO-220FL	50	20	1,000	5	5,000	532×33×7.0	555×164×50	575×290×180

使用说明 / Notices